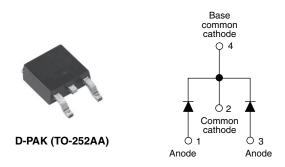


Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 3 A



PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	2 x 3 A						
V _R	50 V, 60 V						
V _F at I _F	0.65 V						
I _{RM}	15 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	6 mJ						

FEATURES

- Popular D-PAK outline
- · Center tap configuration
- · Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBRD650CTPbF, VS-MBRD660CTPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	6	A						
V _{RRM}		50/60	V						
I _{FSM}	t _p = 5 μs sine	490	A						
V _F	$3 A_{pk}, T_J = 125 \ ^{\circ}C \ (per \ leg)$	0.65	V						
TJ	Range	-40 to +150	°C						

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS-MBRD650CTPbF	VS-MBRD660CTPbF	UNITS						
Maximum DC reverse voltage	V _R	50	60	V						
Maximum working peak reverse voltage	V _{RWM}	50	00	v						

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	ER SYMBOL TEST CONDITIONS					UNITS				
Maximum average per leg			50 % duty cycle at T _C = 128 °C, re	3.0						
See fig. 5	per device	I _{F(AV)}	30% duty cycle at $T_{\rm C} = 120\%$ C, re	6	A					
Maximum peak one cycle non-repetitive surge current See fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated		490				
		I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied		75				
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6	mJ				
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.6	А				

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COMPLIANT



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ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CO	VALUES	UNITS						
		3 A	T _{.1} = 25 °C	0.7	V					
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	6 A	1j=25 0	0.9						
See fig. 1		3 A	T _J = 125 °C	0.65						
		6 A	1j = 125 C	0.85						
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Deted V	0.1	mA					
See fig. 2		T _J = 125 °C	V _R = Rated V _R	15						
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		145	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 r	5.0	nH						
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs						

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance,	per leg	Build	DC operation	6					
junction to case	per device	R _{thJC}	See fig. 4	3	°C/W				
Maximum thermal resistance, junction to ambient		R _{thJA}		80					
Approvimate weight				0.3	g				
Approximate weight				0.01	oz.				
Marking device			Case style D-PAK (similar to TO-252AA)	MBRD650CT					
			Case style D-FAN (Similar to TO-252AA)	MBRD660CT					

Note

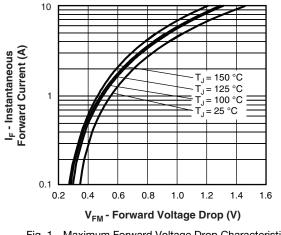
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

VS-MBRD650CTPbF, VS-MBRD660CTPbF

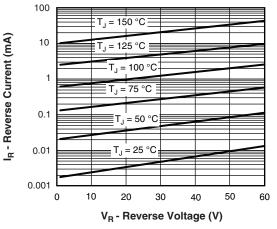


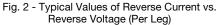


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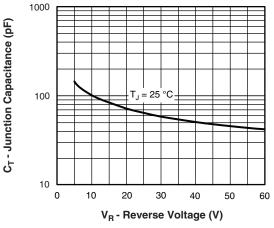


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

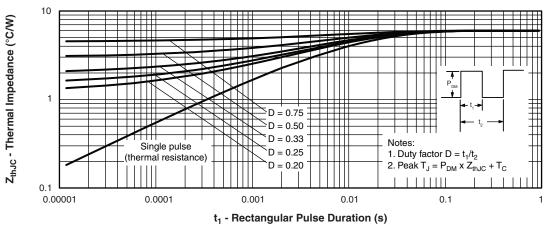
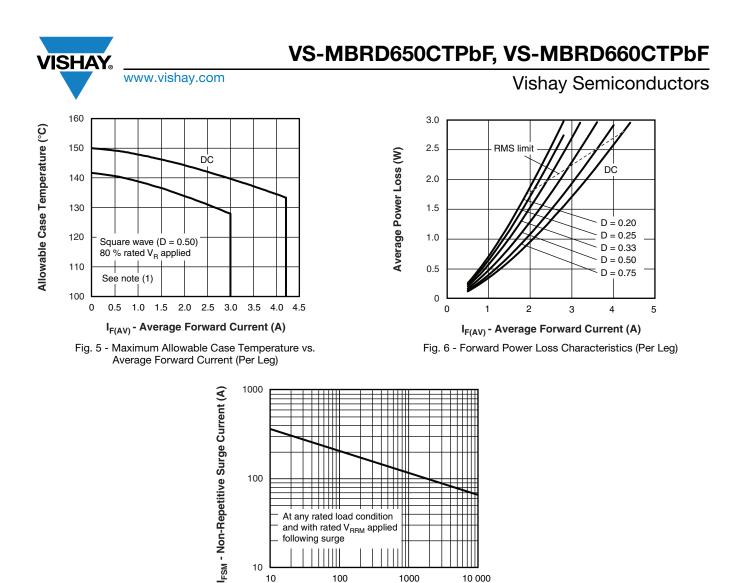


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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t_p - Square Wave Pulse Duration (μs)

1000

10 000

100

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R

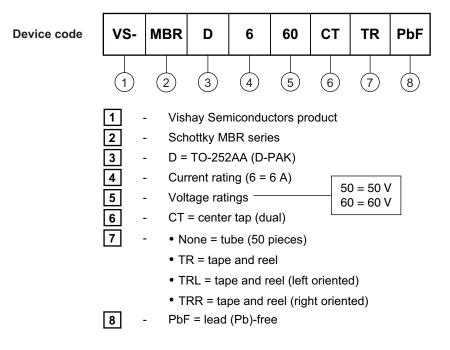
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VS-MBRD650CTPbF, VS-MBRD660CTPbF

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ORDERING INFORMATION TABLE



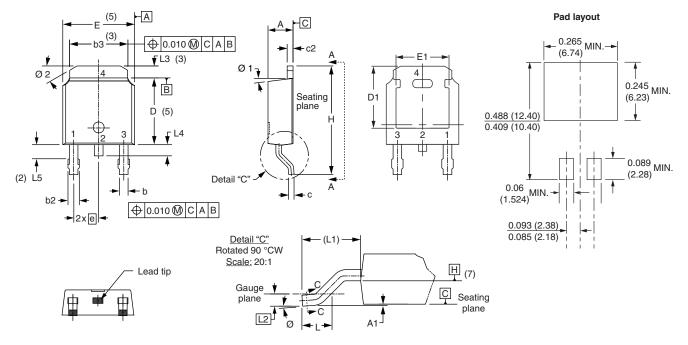
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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